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Spin-orbit dependence of anisotropic current-induced spin polarization

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Studies of the current-induced spin polarization (CISP) have been recently reinvigorated due to the discoveries of CISP in some burgeoning materials such as oxide interfaces, van der Waals and topological quantum materials. Here, we investigate the CISP in two-dimensional systems for different types of spin-orbit coupling (SOC) using the Boltzmann transport theory. We find an anisotropic response of CISP to the current direction which strongly depends on the type of SOC. We demonstrate that the CISP is non-linear with respect to the SOC magnitude, depends on the Fermi energy, and exhibits two different transport regimes for low or high carrier density. Finally, we propose a magnetoresistance device which can exploit the predicted CISP anisotropy.

I. INTRODUCTION

Current-induced spin polarization (CISP) is a nonequilibrium spin polarization induced in a conductor with spinorbit coupling (SOC) by passing an electric current^{1,2}. Jointly with the anomalous Hall effect (AHE)³ and the spin Hall effect (SHE)^{4,5}, the CISP represents a charge-to-spin conversion which is interesting for spintronics⁶. However, unlike the AHE/SHE and tunneling AHE/SHE 7,8 generating spin accumulation at the edges of the conductor, the CISP is spatially homogeneous. The CISP effect was originally proposed by Ivchenko and Pikus⁹ for semiconductors lacking spaceinversion symmetry. Later, it was theoretically explored in a two-dimensional electron gas (2DEG) with Dresselhaus SOC (DSOC) by Aronov et al.^{10,11} and Rashba SOC (RSOC) by Edelstein¹². The latter phenomenon is known as the Edelstein effect. Owing to the spin polarization being generated and controlled in nonmagnetic materials by purely electrical means, the CISP offers promising applications in all-electric spintronic devices^{13,14,15,16,17}. Recently, CISP has been experimentally observed in various 2D systems such as a Bi/Ag bilayer^{18,19}, surface of topological insulator Bi₂Se₃^{20,21}, oxide interfaces LaAlO₃/SrTiO₃^{22,23,24}, a van der Waals heterostructure²⁵, and ferroelectric materials ²⁶, ²⁷. In the above systems, the combination of broken inversion symmetry and strong SOC derived from heavy elements results in RSOC, which is critical for generation of CISP.

On the theoretical side, CISP has been extensively studied for 2DEGs^{28,29,30,31,32,33,34}. For example, Silsbee developed a theoretical model for the detection of CISP via electrical measurements²⁸. Trushin and Schliemann investigated the anisotropy of CISP for the 2DEG with RSOC and DSOC in the high-density limiting case²⁹. Johansson *et al.* explored the anisotropy of electron mass and RSOC on the CISP within the semiclassical Boltzmann transport theory³³. Most of these works, however, focused on RSOC and derived formula for CISP formula up to the linear order in SOC magnitude and under high-density regime approximation. Here, using Boltzmann transport theory, we provide a systematic investigation of anisotropic CISP for different types of SOC and explore the Fermi energy dependence beyond the linear order in SOC approximation. We show that the CISP is highly anisotropic, both in magnitude and direction, and strongly depends on the type of SOC. We demonstrate a very different behavior of the CISP as a function the Fermi energy, depending on the Fermi contour topology.

The rest of the paper is organized as follows. In Sec. II, we describe the Hamiltonian model and present the theoretical formalism and general formula for CISP calculation. In Sec. III, we present the results for spin textures and discuss the topology of the Fermi contours. In Sec. IV, we present the analytical results of CISP for different types of SOC based on the Boltzmann transport theory. Finally, in Sec. IV, we discuss the obtained results and make conclusions.

II. THEORETICAL FORMALISM

We consider a single-particle Hamiltonian describing a 2D system with SOC as follows

$$H = \frac{\hbar^2 k^2}{2m} + \mathbf{\Omega} \bullet \mathbf{\sigma} \ . \tag{1}$$

Here the first term is the kinetic energy with *m* being the electron effective mass, \hbar the reduced Planck's constant, and $\mathbf{k} = (k_x, k_y) = k(\cos\phi, \sin\phi)$ the wavevector given in the Cartesian or polar coordinates where ϕ is the azimuthal angle.

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The second term represents the SOC with Ω being the spinorbit field (SOF) defined in **k** space and $\boldsymbol{\sigma} = (\sigma_x, \sigma_y, \sigma_z)$ the Pauli vector. Note that *m* is assumed to be isotropic in **k** space. The eigenvalues $E_{\mathbf{k}s}$ with $s = \pm 1$ being the spin index and normalized eigenstates $\psi_{\mathbf{k}s}$ of Hamiltonian (1) take the form

$$E_{\mathbf{k}s} = \frac{\hbar^2 k^2}{2m} + s\Omega \tag{2}$$

and

$$\psi_{\mathbf{k}s} = \frac{e^{i\mathbf{k}\cdot\mathbf{r}}}{\sqrt{2\Omega(\Omega - s\Omega_z)}} \begin{bmatrix} \Omega_x - i\Omega_y \\ s\Omega - \Omega_z \end{bmatrix}, \qquad (3)$$

respectively, where $\Omega = \sqrt{\Omega_x^2 + \Omega_y^2 + \Omega_z^2}$. The expectation values of the spin operator can be obtained as

$$\mathbf{s}_{\mathbf{k}s} = \frac{\hbar}{2} \langle \psi_{\mathbf{k}s} | \mathbf{\sigma} | \psi_{\mathbf{k}s} \rangle = s \frac{\hbar}{2\Omega} (\Omega_x, \Omega_y, \Omega_z).$$
(4)

Being considered as a function of wave vector \mathbf{k} , Eq. (4) determines the spin texture in \mathbf{k} space.

At the equilibrium conditions, the system is characterized by the equilibrium Fermi distribution function $f_{\mathbf{k}s}^0$ and the net spin polarization is zero namely $\mathbf{s} = \sum_{s} \int \mathbf{s}_{\mathbf{k}s} f_{\mathbf{k}s}^0 d\mathbf{k} = 0$. This follows from time-reversal symmetry, which enforces $\mathbf{s}_{\mathbf{k}} = -\mathbf{s}_{-\mathbf{k}}$ and $f_{\mathbf{k}s}^0 = f_{-\mathbf{k}s}^0$. When an external electric field $\boldsymbol{\varepsilon}$ is applied, the Fermi contour in \mathbf{k} space is displaced by $\delta \mathbf{k}$, which is antiparallel to the direction of $\boldsymbol{\varepsilon}$. The magnitude of $\delta \mathbf{k}$ is determined by the collisions of electrons with impurities and phonons³⁵. Under the non-equilibrium conditions, time reversal symmetry breaks and the distribution function $f_{\mathbf{k}s}$ deviates from $f_{\mathbf{k}s}^0$, so that $f_{\mathbf{k}s} = f_{\mathbf{k}s}^0 + \delta f_{\mathbf{k}s}$ resulting in the non-zero net spin polarization $\delta \mathbf{s}$ given by

$$\delta \mathbf{s} = \sum_{s} \int \mathbf{s}_{\mathbf{k}s} \delta f_{\mathbf{k}s} d\mathbf{k} \quad . \tag{5}$$

To obtain δs from Eq. (5), one needs first to calculate s_{ks} using Eq. (4) and δf_{ks} by solving the Boltzmann transport equation. The latter is generally given by³⁵

$$\frac{\partial f_{\mathbf{k}s}^{o}}{\partial E_{\mathbf{k}s}} (\mathbf{v}_{\mathbf{k}s} \bullet e\mathbf{\epsilon}) = \sum_{\mathbf{k}'s'} (\delta f_{\mathbf{k}s} - \delta f_{\mathbf{k}'s'}) Q_{\mathbf{k}'s'}^{\mathbf{k}s}, \tag{6}$$

where $\mathbf{v}_{\mathbf{k}s}$ is the group velocity and $Q_{\mathbf{k}'s'}^{\mathbf{k}s}$ is the scattering probability from state $|\mathbf{k}'s'\rangle$ to state $|\mathbf{k}s\rangle$. According to the Fermi golden rule, $Q_{\mathbf{k}'s'}^{\mathbf{k}s}$ takes the form

$$Q_{\mathbf{k}'s'}^{\mathbf{k}s} = \frac{2\pi}{\hbar} \left| \left\langle \mathbf{k}s \left| V \left| \mathbf{k}'s' \right\rangle \right|^2 \delta \left(E_{\mathbf{k}s} - E_{\mathbf{k}'s'} \right),$$
(7)

where *V* is an impurity scattering potential. Assuming that the scattering potential is short-ranged, i.e. $V(\mathbf{r}) = V_0 \delta(\mathbf{r})$, and using Eq. (3), we arrive at the following equation for $Q_{\mathbf{k}'s'}^{\mathbf{k}s}$

$$Q_{\mathbf{k}'s'}^{\mathbf{k}s} = \frac{2\pi n V_0^2}{\hbar} \Big[1 + ss' \cos\left(\gamma_{\mathbf{k}} - \gamma_{\mathbf{k}'}\right) \Big] \delta\left(E_{\mathbf{k}s} - E_{\mathbf{k}'s'}\right).$$
(8)

Here *n* is the impurity concentration, $\gamma_{\mathbf{k}} = \tan^{-1}(\Omega_y / \Omega_x)$, and we assume $\Omega_z = 0$. Plugging Eq. (8) into Eq. (6), we obtain

$$\frac{\partial f_{\mathbf{k}s}^{0}}{\partial E_{\mathbf{k}s}} (\mathbf{v}_{\mathbf{k}s} \bullet e\mathbf{\epsilon}) = \frac{nV_{0}^{2}}{2\pi\hbar} \sum_{s'} \int d\mathbf{k} \, \left(\delta f_{\mathbf{k}s} - \delta f_{\mathbf{k}'s'}\right) [1 + ss'\cos(\gamma_{\mathbf{k}} - \gamma_{\mathbf{k}'})] \delta(E_{\mathbf{k}s} - E_{\mathbf{k}'s'}). \tag{9}$$

In the following, we adopt the constant relaxation time approximation, which has been widely used previously^{1,28,31,36}. Within such approximation, $\delta f_{\mathbf{ks}} = e\tau(\mathbf{v}_{\mathbf{ks}} \cdot \mathbf{\epsilon}) \partial f_{\mathbf{ks}}^0 / \partial E_{\mathbf{ks}}$, where τ is the constant relaxation time. In a zero-temperature limit, $-\partial f_{\mathbf{ks}}^0 / \partial E_{\mathbf{ks}} = \delta(E_{\mathbf{ks}} - E_F)$, and the integration in Eq. (5) can be carried out over the Fermi contour S_F , namely^{31,36}

$$\delta \mathbf{s} = -\frac{e\tau}{(2\pi)^2} \sum_{s} \int \frac{\mathbf{s}_{\mathbf{k}s} \left(\mathbf{v}_{\mathbf{k}s} \bullet \mathbf{\epsilon} \right)}{\hbar |\mathbf{v}_{\mathbf{k}s}|} dS_F.$$
(10)

Analogously, the current density \mathbf{j}_e is given by³⁵

$$\mathbf{j}_{e} = \frac{e^{2}\tau}{\left(2\pi\right)^{2}} \sum_{s} \int \frac{\mathbf{v}_{\mathbf{k}s}\left(\mathbf{v}_{\mathbf{k}s} \bullet \boldsymbol{\varepsilon}\right)}{\hbar |\mathbf{v}_{\mathbf{k}s}|} dS_{F}.$$
(11)

Since $\delta \mathbf{s}$ is an implicit function of \mathbf{j}_e , one can obtain $\delta \mathbf{s}$ as a function of \mathbf{j}_e by combing Eqs. (10) and (11).

III. SPIN TEXTURE AND FERMI CONTOUR TOPOLOGY

TABLE I. The SOFs Ω and spin textures **s** for four different SOC types. α , β , γ and λ are the linear SOC parameters.

SOC	Ω	s (in <i>ħ</i> /2)
RSOC	$\alpha(-k_y, k_x, 0)$	$\pm (-k_y, k_x, 0)/k$
DSOC	$\beta(k_x, -k_y, 0)$	$\pm (k_x, -k_y, 0)/k$
WSOC	$\gamma(k_x, k_y, 0)$	$\pm (k_x, k_y, 0)/k$
PSOC	$\lambda \big(k_x - k_y \big) (1,1,0)$	$\pm \operatorname{sgn}(k_x - k_y)(1,1,0)/\sqrt{2}$

Here we consider four different types of SOC, namely RSOC, DSOC, Weyl (WSOC) and persistent-spin-texture (PSOC) types. The corresponding SOFs Ω and calculated spin textures **s** are listed in Table I. Fig. 1 shows the schematic plots of the Fermi contours and spin textures when Fermi energy $E_F > 0$. From Eq. (2) and Table 1, the energy splitting $E_+ - E_$ for RSOC, DSOC, and WSOC is proportional to *k*, indicating the isotropic energy splitting in **k** space, as seen from Figs. 1(a), (b) and (c). While for PSOC, the energy splitting $E_+ - E_-$ is proportional to $k|\cos\phi - \sin\phi|$, indicating that the energy splitting is maximum at $\phi = 3\pi/4$, $7\pi/4$, and zero at $\phi = \pi/4$, $5\pi/4$, as seen from Fig. 1(d). For RSOC, when moving over the Fermi contour, the spin rotates in the same direction as ϕ and is always perpendicular to **k**. In the case of DSOC, the spin rotates in the opposite direction to ϕ and thus can make any angle to **k** depending on ϕ . For WSOC, the spin is ether parallel or antiparallel to **k**. In the case of PSOC, the spin is unidirectional and thus independent of **k**. The above different types of SOC appear in realistic materials³⁷, such as RSOC in 2D materials^{38,39}, DSOC in ferroelectric HfO₂⁴⁰, WSOC in elemental Te and Se^{41,42}, and PSOC in BiInO₃⁴³.

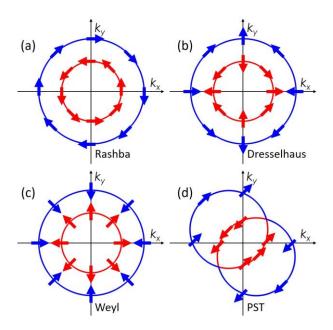


FIG. 1. Schematic Fermi contours ($E_F > 0$ case) and spin textures for (a) RSOC, (b) DSOC, (c) WSOC, and (d) PSOC. Arrows indicate the spin directions while the red and blue contour lines represent the E_+ and E_- energy branches, respectively.

It is noteworthy that the topology of the Fermi contour depends on E_F . Fig. 1 assumes that the Fermi energy E_F crosses both energy branches E_+ and E_- , i.e. $E_F > 0$. However, for $E_F < 0$, as shown in Fig. 2(a) for RSOC, DSOC, and WSOC, the E_F crosses only the lower band E_- and the Fermi contour is an annulus. E_F crosses both bands only when $E_F > 0$, where the Fermi contour evolves into two circles (Fig. 2(b)). In the case of PSOC, for $E_F < 0$, the E_F crosses only the lower band E_- and the Fermi contours are two well-separated circles centered at wave vectors $m\alpha/\hbar^2(-\sqrt{2}, \sqrt{2})$ and $m\alpha/\hbar^2(\sqrt{2}, -\sqrt{2})$, which are E_F independent (Fig. 2(c)). For $E_F > 0$, the E_F crosses both E_+ and E_- , and the Fermi contour is characterized by two intersecting circles centered at $\sqrt{2m^2\alpha^2 + mE_F}/\hbar(-1, 1)$ and $\sqrt{2m^2\alpha^2 + mE_F}/\hbar(1, -1)$, which are E_F dependent. We see that the topology of the Fermi contour changes as E_F varies, and there is a topological transition point at $E_F = 0$. As we will demonstrate in the following sections, the topology of the Fermi contour strongly affects the CISP.

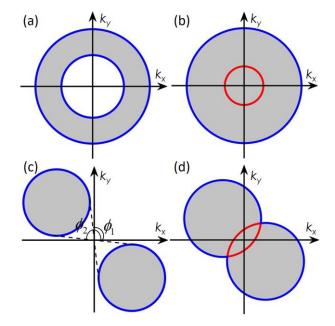


FIG. 2. Schematic Fermi contours for (a, b) RSOC, DSOC or WSOC and (c, d) PSOC. (a, c) for $E_F < 0$, and (b, d) for $E_F > 0$. The gray shaded regions represent the electron occupied states. In (c), $\phi_{1,2}$ ($\phi_1 + \phi_2 = 3\pi/2$) denotes the critical angles separating the electron occupied and unoccupied states. Red and blue contour lines represent the E_+ and E_- energy branches, respectively.

IV. CURRENT-INDUCED SPIN POLARIZARION

In this section, we derive the expressions for CISP for four different types of SOC. The electric field is assumed to have form $\mathbf{\varepsilon} = \varepsilon(\cos\varphi, \sin\varphi)$, where φ is the azimuthal angle in the polar coordinate system.

A. Rashba type

From Eq. (2) and Table 1, the eigenvalue E_s for RSOC is given by $E_s = \hbar^2 (k + sk_R)^2 / (2m) - E_R$, where $k_R = m\alpha/\hbar^2$ and $E_R = m\alpha^2/(2\hbar^2)$. Accordingly, the group velocity can be calculated as $\mathbf{v}_s = \hbar \mathbf{k}/m + s \alpha \mathbf{k}/(\hbar k)$. From $E_s = E_F$, we obtain the Fermi wave vector as follows

$$\begin{cases} k_{F\eta} = k_R - \eta \sqrt{k_R^2 - k_0^2}, & E_c < E_F \le 0\\ k_{Fs} = \sqrt{k_R^2 + k_0^2} - sk_R, & E_F > 0 \end{cases},$$
 (12)

where $\eta = \pm 1$, $E_c = -E_R$ denotes the band minimum and $k_0 = \sqrt{2m|E_F|/\hbar^2}$.

When $E_c < E_F \le 0$, from Eqs. (10) and (11), $\delta \mathbf{s}$ is calculated as

$$\delta \mathbf{s} = \sum_{\eta} \frac{e\varepsilon\tau}{8\pi^2} \int_0^{2\pi} {-\sin\phi \choose \cos\phi} \cos(\phi - \varphi) (-\eta k_{F\eta}) d\phi$$

$$= \frac{e\varepsilon\tau \sqrt{2m(E_F + E_R)}}{4\pi\hbar} {-\sin\phi \choose \cos\phi},$$
(13)

and \mathbf{j}_e is calculated as

$$\mathbf{j}_{e} = \sum_{\eta} \frac{e^{2} \tau \mathbf{\epsilon}}{4\pi^{2} \hbar} \int_{0}^{2\pi} \left| \frac{\hbar k_{F\eta}}{m} - \frac{\alpha}{\hbar} \right| k_{F\eta} \cos^{2} \left(\phi - \varphi \right) d\phi$$

$$= \frac{e^{2} \tau \mathbf{\epsilon}}{\pi \hbar^{2}} \sqrt{E_{R} \left(E_{F} + E_{R} \right)}.$$
(14)

When $E_F > 0$, in a similar way, δs is calculated as

$$\delta \mathbf{s} = -\sum_{s} \frac{e\varepsilon\tau}{8\pi^{2}} \int_{0}^{2\pi} \left(\frac{-\sin\phi}{\cos\phi} \right) \cos(\phi - \phi) s k_{Fs} d\phi$$

$$= \frac{e\varepsilon\tau \sqrt{2mE_{R}}}{4\pi\hbar} \left(\frac{-\sin\phi}{\cos\phi} \right),$$
(15)

and \mathbf{j}_e is calculated as

$$\mathbf{j}_{e} = \sum_{s} \frac{e^{2} \tau \mathbf{\epsilon}}{4\pi^{2} \hbar} \int_{0}^{2\pi} \frac{\hbar}{m} \sqrt{k_{R}^{2} + k_{0}^{2}} k_{Fs} \cos^{2}(\phi - \phi) d\phi$$

$$= \frac{e^{2} \tau \mathbf{\epsilon}}{\pi \hbar^{2}} (E_{F} + E_{R}).$$
(16)

Thus, $\delta \mathbf{s}$ as a function of j_e and E_F for RSOC is given by

$$\delta \mathbf{s} = \begin{cases} \frac{\sqrt{2m}\hbar j_e}{4e\sqrt{E_R}} \begin{pmatrix} -\sin\varphi\\\cos\varphi \end{pmatrix}, & E_c < E_F \le 0\\ \frac{\sqrt{2mE_R}\hbar j_e}{4e(E_F + E_R)} \begin{pmatrix} -\sin\varphi\\\cos\varphi \end{pmatrix}, & E_F > 0 \end{cases}$$
(17)

In the high-density regime, i.e. when $E_F \gg E_R$, $\delta \mathbf{s}$ becomes linearly dependent on the RSOC parameter α , which is consistent with the previous work^{30,31,32}. In general, however, $\delta \mathbf{s}$ is a non-linear function of α . Moreover, as follows from Eq. (17), $\delta \mathbf{s}$ is inversely proportional to α in the low density regime when $E_c < E_F \le 0$. It is noteworthy that the relaxation time τ is assumed to be spin dependent in some previous works^{1,28,31}, namely $\tau_s = \tau (1 - s k_R/k_0)$ up to linear order in α when $E_F \gg E_R$. Taking this into account, $\delta \mathbf{s}$ will be modified accordingly as

$$\delta \mathbf{s} = \frac{e\varepsilon\tau\sqrt{2mE_R}}{4\pi\hbar} \left(1 + \sqrt{1 + \frac{E_R}{E_F}}\right) \begin{pmatrix} -\sin\varphi\\\cos\varphi \end{pmatrix},\tag{18}$$

and \mathbf{j}_e is

$$\mathbf{j}_{e} = \frac{e^{2}\tau\boldsymbol{\varepsilon}}{\pi\hbar^{2}} \Bigg[E_{F} + E_{R} \Bigg(1 + \sqrt{1 + \frac{E_{R}}{E_{F}}} \Bigg) \Bigg].$$
(19)

Eq. (17) is thus modified as

$$\delta \mathbf{s} = \begin{cases} \frac{\sqrt{2m\hbar j_e}}{4e\sqrt{E_R}} \begin{pmatrix} -\sin\varphi\\\cos\varphi \end{pmatrix}, & E_e < E_F \le 0\\ \frac{\sqrt{2mE_R}\hbar j_e}{2e(E_F + 2E_R)} \begin{pmatrix} -\sin\varphi\\\cos\varphi \end{pmatrix}, & E_F > 0 \end{cases}$$
(20)

It is seen that there is a factor of 2 difference when $E_F \gg E_R$ between Eq. (17) and Eq. (20), which is in line with previous work³¹. On the other hand, as seen from Eqs. (13), (15) describing ε dependence of δs and (17) describing j_e dependence of δs , the E_R dependence of δs is completely different for a constant-voltage experiment and a constantcurrent experiment. For the former, $\delta s \sim \sqrt{E_F + E_R}$ when $E_c < E_F \le 0$ and $\delta s \sim \sqrt{E_R}$ when $E_F > 0$. For the later, $\delta s \sim 1/\sqrt{E_R}$ when $E_c < E_F \le 0$ and $\delta s \sim \sqrt{E_R}/(E_F + E_R)$ when $E_F > 0$.

B. Dresselhaus type

For DSOC, the eigenvalue E_s is given by $E_s = \hbar^2 (k + sk_D)^2 / (2m) - E_D$, where $k_D = m\beta/\hbar^2$ and $E_D = m\beta^2/(2\hbar^2)$. In a similar way as in Sec. A above, we obtain for $\delta \mathbf{s}$ a function of j_e and E_F :

$$\delta \mathbf{s} = \begin{cases} \frac{\sqrt{2m\hbar j_e}}{4e\sqrt{E_D}} \begin{pmatrix} \cos\varphi \\ -\sin\varphi \end{pmatrix}, & E_c < E_F \le 0\\ \frac{\sqrt{2mE_D}\hbar j_e}{4e(E_F + E_D)} \begin{pmatrix} \cos\varphi \\ -\sin\varphi \end{pmatrix}, & E_F > 0 \end{cases}$$
(21)

where $E_c = -E_D$ denotes the band minimum.

C. Weyl type

For WSOC, the eigenvalue E_s is given by $E_s = \hbar^2 (k + sk_W)^2 / (2m) - E_W$, where $k_W = m\gamma/\hbar^2$ and $E_W = m\gamma^2/(2\hbar^2)$. Using a similar calculation, we obtain for $\delta \mathbf{s}$ a function of j_e and E_F :

$$\delta \mathbf{s} = \begin{cases} \frac{\sqrt{2m}\hbar j_e}{4e\sqrt{E_w}} \begin{pmatrix} \cos\varphi\\\sin\varphi \end{pmatrix}, & E_c < E_F \le 0\\ \frac{\sqrt{2mE_w}\hbar j_e}{4e(E_F + E_w)} \begin{pmatrix} \cos\varphi\\\sin\varphi \end{pmatrix}, & E_F > 0 \end{cases}$$
(22)

where $E_c = -E_W$ denotes the band minimum.

D. PST type

For PSOC, the eigenvalue E_s is given by $E_s = \hbar^2 (k + sk_{\phi})^2 / (2m) - E_{\phi}$, where $k_{\phi} = \sqrt{2}m\lambda |\cos\phi - \sin\phi|/\hbar^2$ and $E_{\phi} = m\lambda^2 (\cos\phi - \sin\phi)^2/\hbar^2$. Accordingly, the group velocity is calculated as $\mathbf{v}_s = \hbar \mathbf{k}/m + s\sqrt{2}\lambda/\hbar \operatorname{sgn}(\cos\phi - \sin\phi)(1, -1)$. From $E_s = E_F$, we obtain for the Fermi wave vector

$$\begin{cases} k_{F\eta} = k_{\phi} - \eta \sqrt{k_{\phi}^2 - k_0^2}, & E_c < E_F \le 0\\ k_{Fs} = \sqrt{k_{\phi}^2 + k_0^2} - sk_{\phi}, & E_F > 0 \end{cases},$$
(23)

where $E_c = -2m\lambda^2/\hbar^2 = -E_P$ denotes the band minimum. When $E_c < E_F \le 0$, δs can be calculated as

$$\delta \mathbf{s} = \frac{\sqrt{2m}e\varepsilon\tau \left(E_F + E_P\right)}{6\pi^2\hbar\sqrt{E_P}} \left(\cos\varphi - \sin\varphi\right) \begin{pmatrix} 1\\ 1 \end{pmatrix},\tag{24}$$

and \mathbf{j}_{e} is calculated as

$$\mathbf{j}_{e} = \frac{e^{2} \tau \mathbf{\epsilon}}{\pi^{2} \hbar^{2}} \Big[2 \Big(E_{F} + E_{P} \Big) \\ + \Big(\frac{14}{15} E_{F} + \frac{2}{15} E_{P} + \frac{4 E_{F}^{2}}{5 E_{P}} \Big) \sin 2\varphi \Big].$$
(25)

For $E_F > 0$, analytic expressions for $\delta \mathbf{s}$ and \mathbf{j}_e can be obtained within the high-density regime assumption, i.e. $E_F \gg E_P$. For $\delta \mathbf{s}$ we find

$$\delta \mathbf{s} = \frac{e\varepsilon\tau\sqrt{m} \left(E_{P}\right)^{3/2}}{16\sqrt{2}\pi\hbar\sqrt{E_{F} \left(E_{F}+E_{P}\right)}} \left(\cos\varphi-\sin\varphi\right) \begin{pmatrix}1\\1\end{pmatrix}, \quad (26)$$

and for \mathbf{j}_e we find

$$\mathbf{j}_{e} = \frac{e^{2}\tau \mathbf{\epsilon}}{4\pi\hbar^{2}\sqrt{E_{F} + E_{P}}} \Bigg[4E_{F}\sqrt{E_{F}} + 5E_{P}\sqrt{E_{F}} - \frac{2E_{P}^{2}}{\sqrt{E_{F}}} + \left(\frac{2E_{P}^{2}}{\sqrt{E_{F}}} - \frac{E_{P}\sqrt{E_{F}}}{2}\right) \sin 2\varphi \Bigg].$$

$$(27)$$

Details of the derivation of Eqs. (24)-(27) are presented in Appendix A. Noteworthy is the fact that, although the analytic

expressions given by Eqs. (26) and (27) are derived within the high-density regime, the φ dependent functional relationships $\delta \mathbf{s} \sim (\cos \varphi - \sin \varphi)$ and $\mathbf{j}_e \sim \sin 2\varphi$ hold exactly, as seen from Eqs. (A3) and (A4).

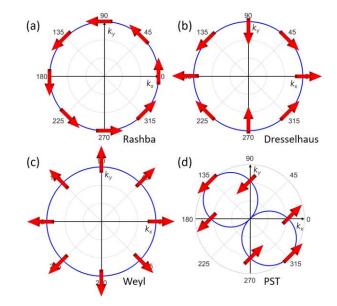


Fig. 3. δs as a function of the direction of the electric field φ in polar coordinates for (a) RSOC, (b) DSOC, (c) WSOC and (d) PSOC. Blue lines represent the magnitude while the red arrows indicate the direction of δs .

Fig. 3 shows $\delta \mathbf{s}$ as a function of φ including magnitude δs (blue lines) and direction (red arrows). For RSOC, DSOC, and WSOC, shown in Fig. 3(a-c), from Eqs. (17), (21), and (22), we see that δs is φ independent, indicating that δs is isotropic. However, the direction of $\delta \mathbf{s}$ is strongly φ dependent. In fact, the $\delta \mathbf{s}$ orientation mirrors the spin textures shown in Figs. 1(a-c) (the inner branches indicated by red lines). In the case of PSOC, from Eqs. (24) and (26), δs as a function of φ is determined by $|\cos \varphi - \sin \varphi|$, indicating perfect anisotropy of δs , so that δs is zero at $\varphi = \pi/4$, $5\pi/4$ and δs is maximum at $\varphi = 3\pi/4$, $7\pi/4$. Like for the other types of SOC, the direction of $\delta \mathbf{s}$ for PSOC mirrors the spin texture (Fig. 1(d), the inner branch indicated by red line).

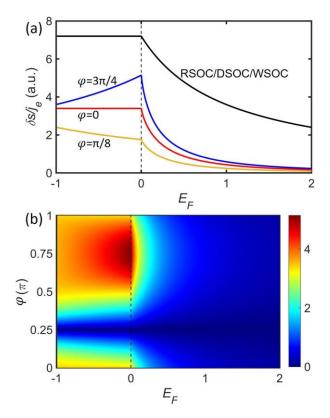


Fig. 4. (a) CISP efficiency $\delta s/j_e$ as a function of E_F (in units of $|E_c|$) for RSOC, DSOC, and WSOC (black line) and PSOC when $\varphi = 0$ (red line), $\varphi = \pi/8$ (orange line) and $\varphi = 3\pi/4$ (blue line). (b) CISP efficiency $\delta s/j_e$ (color) as a function of E_F and the direction of the electric field φ for PSOC. The SOC parameters are assumed to be $\alpha = \beta = \gamma = 2\lambda = 1.0$ eV Å and electron effective mass is m = 0.5, under which the band minima E_c are the same for the different types of SOC. The vertical dash lines indicate the topological transition point of the Fermi contour.

Fig. 4(a) shows the E_F dependence of the CISP efficiency $\delta s/j_e$, which is defined as the ratio of the magnitudes of δs and j_e . For PSOC and the energy range of $E_F > 0$, $\delta s/j_e$ is obtained using numerical calculations. As seen from Fig. 4 (a), in the case of RSOC, DSOC, and WSOC, when $E_c < E_F \le 0$, $\delta s/j_e$ is a constant. When $E_F > 0$, $\delta s/j_e$ decreases monotonically as E_F increases, consistent with Eqs. (17)-(22). The similar behavior was also observed in the graphene on a transition metal dichalcogenide monolayer with combination of RSOC and Zeeman SOC⁴⁴.

Such a dissimilar behavior of $\delta s/j_e$ versus E_F can be understood from the analysis the Fermi contour topology. Taking RSOC as an example, we see from Fig. 2(a) that for $E_c < E_F \le 0$, the Fermi surface represents two SOC-split concentric circles with the *same* spin configurations. As a result, both δs and j_e are proportional to the sum of the their perimeters, which according to Eq. (12) is proportional to $\sqrt{E_F + E_R}$. This yields the same E_F dependence of δs and j_e , i.e. $\delta s \sim j_e \sim \sqrt{E_F + E_R}$, and hence the constant $\delta s/j_e$. On the contrary, when $E_F > 0$, as seen from Fig. 2(b), the two SOCsplit concentric Fermi circles have *opposite* spin configurations. As a result, while j_e is still proportional to the sum of the circumferences, δs is proportional to their difference. This leads to the different E_F dependence of δs and j_e , which according to Eq. (12) is given by $\delta s \sim \sqrt{E_R}$ and $j_e \sim \sqrt{E_F + E_R}$, resulting in $\delta s/j_e \sim 1/\sqrt{E_F + E_R}$. The same argument applies to DSOC and WSOC.

In the case of PSOC, the two Fermi contours do not represent concentric circles (Figs. 2 (c-d)) and the behavior of $\delta s/j_e$ as a function of E_F is more complicated. As seen from Fig. 4(a), when $\varphi = 0$ (red line), $\delta s/j_e$ is a constant in the energy range $E_c < E_F \le 0$ and decreases monotonically when $E_F > 0$, consistent with Eqs. (24) and (25). When $\varphi = 3 \pi/4$ (blue line), $\delta s/j_e$ increases (decreases) monotonically in the range $E_c < E_F \le 0$ ($E_F > 0$) as E_F increases, indicating that $\delta s/j_e$ reaches maximum at the transition point $E_F = 0$. When $\varphi = \pi/8$ (orange line), $\delta s/j_e$ decreases monotonically in the whole energy range. Fig. 4(b) shows the $\delta s/j_e$ for PSOC as a function of E_F and electrical field direction φ (with period π). It is seen that the optimal condition, at which $\delta s/j_e$ reaches maximum, appears at $E_F = 0$ and $\varphi = 3\pi/4$.

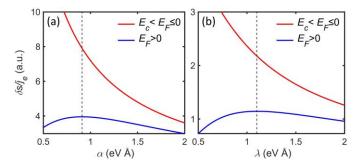


Fig. 5. CISP efficiency $\delta s/j_e$ as a function of SOC parameters α and λ for (a) RSOC/DSOC/WSOC type and (b) PSOC type. The other parameters are assumed to be m = 0.5, $|E_F| = 27.2$ meV and $\varphi = 3\pi/4$ in (b). The dashed lines denote the critical points, at which $\delta s/j_e$ reaches maximum when $E_F > 0$.

Fig. 5 shows the CISP efficiency $\delta s/j_e$ as a function of SOC parameters. In the case of RSOC, DSOC and WSOC shown in Fig. 5(a), when $E_c < E_F \le 0$, $\delta s/j_e$ decreases monotonically as α increases due to $\delta s/j_e \sim 1/\alpha$ as seen from Eq. (17). When $E_F > 0$, $\delta s/j_e$ becomes maximum at the critical point $\alpha = \hbar \sqrt{2E_F/m}$, as obtained from Eq. (17). In the case of PSOC shown in Fig. 5(b), the λ dependency of $\delta s/j_e$ shows qualitatively similar behavior.

V. DISSUSSION AND CONCLUSIONS

We would like to emphasize the different dependence of the CISP efficiency on the Fermi energy below and above the topological transition point. For RSOC, the CISP efficiency is higher below the transition point than that above the transition point. This follows from reversal of the spin texture at the inner Fermi contour which enhances the induced spin polarization below the transition point due to parallel spin directions on the two SOC-split Fermi contours.

In this low carrier density regime, i.e. when $E_c < E_F \le 0$, the CISP is inversely proportional to α (Eq. (17)), which seems to be counterintuitive. However, one should take into account the fact that reducing α implies, for a given E_F , reducing j_e (Eq. (14)) due to the reduced carrier density. From Eq. (12), the electron density *n* can be calculated as

$$n(E_{F}) = \begin{cases} 2N_{0}\sqrt{E_{R}(E_{F}+E_{R})}, & E_{c} < E_{F} \le 0\\ N_{0}(E_{F}+2E_{R}), & E_{F} > 0 \end{cases}$$
(28)

where $N_0 = m/(\pi\hbar^2)$ is the density of states for a free 2DEG. The critical density at the transition point $E_F = 0$ is $n_0 = m^2 \alpha^2/(\pi\hbar^4)$, which depends quadratically on the RSOC parameter α .

We estimate the critical carrier density n_0 for realistic systems. For a LaAlO₃/SrTiO₃ 2DEG, the Rashba parameter α ranges from 0.015 to 0.043 eV Å⁴⁵, $m = 0.4 m_0$, and we obtain n_0 varying from 2.0×10^9 cm⁻² to 1.6×10^{10} cm⁻². These values of n_0 are much smaller than the typical carrier density of the 2DEG varying from $\sim 1 \times 10^{13}$ to $\sim 1 \times 10^{14}$ cm⁻². Therefore, the high carry density regime is well justified for a LaAlO₃/SrTiO₃ 2DEG.

The situation is however very different for a Bi/Ag system¹⁹, where α =3.05 eV Å, m = 0.35 m_0 , and therefore $n_0 \approx 6.2 \times 10^{13}$ cm⁻². The measured electron density is in the range from 0.5×10^{13} to 4.0×10^{13} cm⁻², which is less than the critical carrier density. This corresponds to the low carrier density regime, where an "anomalous" behavior of the CISP is expected. It would be interesting to experimentally verify the validity of Eq. (17) by investigating the CISP efficiency for a Bi/Ag system with varying carrier concentration.

In this work, we limit our investigation to SOC linear in k and the higher order contributions are neglected, which is appropriate for the description of systems with C_{2v} and C_{4v} point symmetries ⁴⁶. However, for the system with C_{3v} point symmetry⁴⁷, the cubic order correction to CISP is also important and needs to be taken into consideration⁴⁸. Second, the electron effective mass in Eq. (1) is assumed to be isotropic in **k** space. In realistic materials, the effective mass is expected to be **k**-direction dependent. It would be thus interesting to explore the

effect of mass anisotropy on CISP in the future study. Third, we calculate the CISP based on the constant relaxation time approximation. In general, the scattering probability is spin and wavevector dependent. It would be therefore desirable to investigate the CISP beyond the constant relaxation time approximation. It is also to be noted that the vertex corrections are neglected in the relaxation time approximation⁴⁹ and the vertex corrections could lead to quantitative changes of CISP, but it will not alter our main results qualitatively. Furthermore, the SOC effect due to the electron scattering with random potential is ignored in this work. The effect of spin-orbit scattering has been theoretically investigated by previous work³⁴. Fourth, we limit our study to the non-magnetic systems, where the exchange coupling between conduction electron spin and local magnetization is absent. However, CISP can also be induced in magnetic systems with SOC⁵⁰. The interaction between CISP and local magnetization results in a spin torque on the local magnetization^{36, 51, 52}. In addition, the CISP is expected to be dependent on the magnetization orientation due to the magnetically controlled Fermi contours^{53,54,55}. Lastly, a giant SOC has been demonstrated in certain three-dimensional (3D) bulk systems, such as polar semiconductor BiTeI⁵⁶ and ferroelectric crystals^{57,58,59}. Some of these 3D systems exhibit giant SOC, orders of magnitude larger than that in conventional semiconductors, which favors the enhancement of CISP³¹. Besides the SOC magnitude, the spin-torque efficiency, which is defined as the spin torque divided by the current density, is enhanced in 3D systems with RSOC and exchange interaction as compared to 2D systems⁶⁰. It is thus interesting to explore the effect of dimensionality on the CISP efficiency. Finally, the switchable SOC parameters in ferroelectrics by electrically controlled polarization^{40,57,58,59} enables the non-volatile electric control of CISP.

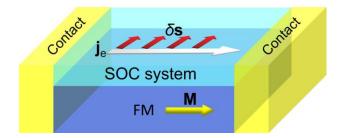


FIG. 6. Schematic illustration of magnetoresistance device due to the interplay of current-direction (j_e , white arrow) dependent CISP δs (red arrow) in SOC conductor layer and local magnetization **M** (yellow arrow) in ferromagnetic (FM) layer.

In summary, we have investigated the anisotropic CISP in two dimensions with different types of SOC using the Boltzmann transport theory. We demonstrated the strong spatial anisotropy of CISP in terms of direction as well as magnitude. Additionally, we showe the CISP efficiency behaves differently as a function of the Fermi energy below and above the topological transition point of the Fermi contour. The anisotropy of CISP can be further used to explore the spindependent transport properties. For example, the electrical conductivity of a bilayer system, which consists of a conducting layer with SOC and ferromagnetic metal layer, is expected to depend on the current direction, as schematically shown in Fig. 6. Such a magnetoresistance effect arises from the interplay between current-direction dependent CISP and local magnetization, as has been recently reported in ferromagnet/heavy metal bilayers⁶¹ and magnetic topological insulator based heterostructures^{62,63}. Conversely, measuring the current direction dependent magnetoresistance offers an efficient way to quantify the type of SOC.

ACKNOWLEDGMENTS

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APPENDIX A: DERIVATION OF EQS. (24)-(27)

From Eq. (10), when $E_c < E_F \le 0$, $\delta \mathbf{s}$ can be calculated as

$$\begin{split} \delta \mathbf{s} &= \sum_{\eta} \frac{e\varepsilon\tau}{8\sqrt{2}\pi^2} \binom{1}{1} \int_0^{2\pi} \operatorname{sgn} \left(\cos\phi - \sin\phi \right) (\hat{v}_k \bullet \hat{\varepsilon}) k_{F\eta} d\phi \\ &= \frac{\sqrt{m}\varepsilon\tau}{8\pi^2 \sqrt{E_F + E_P}} \binom{1}{1} \int_0^{2\pi} \operatorname{sgn} \left(\cos\phi - \sin\phi \right) \left[\left(\frac{2m\lambda^2}{\hbar^3} (1 - 2\sin 2\phi) - \frac{\hbar k_0^2}{m} \right) \cos(\phi - \phi) + \frac{2m\lambda^2}{\hbar^3} \sin(\phi + \phi) \right] d\phi \\ &= -\frac{\sqrt{m}\varepsilon\tau}{4\pi^2 \sqrt{E_F + E_P}} \binom{1}{1} \int_{\phi}^{\phi_2} \left[\left(\frac{2m\lambda^2}{\hbar^3} (1 - 2\sin 2\phi) - \frac{\hbar k_0^2}{m} \right) \cos(\phi - \phi) + \frac{2m\lambda^2}{\hbar^3} \sin(\phi + \phi) \right] d\phi \end{split}$$
(A1)
$$&= -\frac{\sqrt{m}\varepsilon\tau}{4\pi^2 \sqrt{E_F + E_P}} \binom{1}{1} \left[\frac{\hbar k_0^2}{m} (\cos\phi_1 - \cos\phi_2) - \frac{8m\lambda^2}{3\hbar^3} (\cos^3\phi_1 - \cos^3\phi_2) \right] (\cos\phi - \sin\phi) \\ &= \frac{\sqrt{m}\varepsilon\tau (E_F + E_P)}{3\sqrt{2}\pi^2\hbar\sqrt{E_P}} (\cos\phi - \sin\phi) \binom{1}{1}, \end{split}$$

where the critical angles $\phi_{1,2}$ (see Fig. 2(c)) are given by $\phi_{1,2} = \sin^{-1}\left(\frac{\sqrt{2}\hbar^2 k_0}{4m\lambda} \pm \sqrt{\frac{1}{2} - \frac{\hbar^4 k_0^2}{8m^2\lambda^2}}\right)$, as obtained from $|k_{\phi}| = |k_0|$. From Eq. (11), the current density \mathbf{j}_e is calculated as

8

$$\begin{aligned} \mathbf{j}_{e} &= \sum_{\eta} \frac{e^{2} \tau \mathbf{\epsilon}}{4\pi^{2} \hbar} \int_{0}^{2\pi} |v_{F\eta}| \left(\hat{v}_{k} \bullet \hat{\varepsilon} \right)^{2} k_{F\eta} d\phi \\ &= \frac{\sqrt{m}e^{2} \tau \mathbf{\epsilon}}{2\sqrt{2}\pi^{2} \hbar \sqrt{E_{F} + E_{P}}} \sum_{\eta} \int_{\phi}^{\phi_{2}} \left[\frac{\hbar^{2} k_{F\eta}^{3}}{m^{2}} \left(\cos^{2} \phi \cos^{2} \phi + \sin^{2} \phi \sin^{2} \phi \right) + \frac{2\sqrt{2}\lambda k_{F\eta}^{2}}{m} \left(\cos \phi \cos^{2} \phi - \sin \phi \sin^{2} \phi \right) \right. \\ &+ \frac{2\lambda^{2} k_{F\eta}}{\hbar^{2}} + \frac{\hbar^{2} k_{F\eta}^{3}}{2m^{2}} \sin 2\phi \sin 2\phi - \frac{2\lambda^{2} k_{F\eta}}{\hbar^{2}} \sin 2\phi + \frac{\sqrt{2}\lambda k_{F\eta}^{2}}{m} \left(\sin \phi - \cos \phi \right) \sin 2\phi \right] d\phi \end{aligned}$$

$$\begin{aligned} &= \frac{\sqrt{m}e^{2} \tau \mathbf{\epsilon}}{\sqrt{2}\pi^{2} \hbar \sqrt{E_{F} + E_{P}}} \int_{\phi}^{\phi_{2}} \left[\frac{\hbar^{2}}{m^{2}} \left(4k_{\phi}^{3} - 3k_{\phi}k_{0}^{2} \right) \cos^{2} \phi + \frac{2\sqrt{2}\lambda}{m} \left(2k_{\phi}^{2} - k_{0}^{2} \right) \cos \phi + \frac{2\lambda^{2} k_{\phi}}{\hbar^{2}} \right] d\phi \end{aligned}$$

$$\begin{aligned} &= \frac{\hbar^{2}}{2m^{2}} \left(4k_{\phi}^{3} - 3k_{\phi}k_{0}^{2} \right) \sin 2\phi \sin 2\phi - \frac{2\lambda^{2} k_{\phi}}{\hbar^{2}} \sin 2\phi - \frac{2\sqrt{2}\lambda}{m} \left(2k_{\phi}^{2} - k_{0}^{2} \right) \cos \phi \sin 2\phi \right] d\phi \end{aligned}$$

$$\begin{aligned} &= \frac{e^{2} \tau \mathbf{\epsilon}}{\pi^{2} \hbar^{2}} \left[2\left(E_{F} + E_{P} \right) + \left(\frac{14}{15} E_{F} + \frac{2}{15} E_{P} + \frac{4E_{F}^{2}}{5E_{P}} \right) \sin 2\phi \right]. \end{aligned}$$

When $E_F > 0$, $\delta \mathbf{s}$ can be calculated as

$$\begin{split} \delta \mathbf{s} &= -\frac{e\varepsilon\tau}{8\sqrt{2}\pi^2} \binom{1}{1} \sum_s \int_0^{2\pi} \operatorname{sgn} \left(\cos\phi - \sin\phi \right) \left(\hat{v}_{ks} \bullet \hat{\varepsilon} \right) sk_{Fs} d\phi \\ &= \frac{\sqrt{me\varepsilon\tau\lambda}}{4\sqrt{2}\pi^2 \hbar \sqrt{E_F + E_P}} \binom{1}{1} \int_0^{2\pi} \left[2\left(\cos\phi - \sin\phi \right) \cos\left(\phi - \phi\right) - \left(\cos\phi - \sin\phi \right) \right] \sqrt{k_{\phi}^2 + k_0^2} d\phi \\ &= -\frac{\sqrt{me\varepsilon\tau\lambda}}{4\sqrt{2}\pi^2 \hbar \sqrt{E_F + E_P}} \left(\cos\phi - \sin\phi \right) \binom{1}{1} \int_0^{2\pi} \sin 2\phi \sqrt{k_{\phi}^2 + k_0^2} d\phi \end{split}$$
(A3)
$$&\approx -\frac{\sqrt{me\varepsilon\tau\lambda}}{4\sqrt{2}\pi^2 \hbar \sqrt{E_F + E_P}} \left(\cos\phi - \sin\phi \right) \binom{1}{1} \int_0^{2\pi} \sin 2\phi \left(k_0 + \frac{k_{\phi}^2}{2k_0} \right) d\phi \\ &= \frac{e\varepsilon\tau \sqrt{m}(E_P)^{3/2}}{16\sqrt{2}\pi \hbar \sqrt{E_F}(E_F + E_P)} \left(\cos\phi - \sin\phi \right) \binom{1}{1}, \end{split}$$

and \mathbf{j}_{e} is calculated as

$$\begin{aligned} \mathbf{j}_{e} &= \sum_{s} \frac{e^{2} \tau \mathbf{\epsilon}}{4\pi^{2} \hbar} \int_{0}^{2\pi} |v_{ks}| (\hat{v}_{ks} \bullet \hat{\varepsilon})^{2} k_{Fs} d\phi \\ &= \frac{\sqrt{me^{2} \tau \mathbf{\epsilon}}}{4\sqrt{2}\pi^{2} \hbar \sqrt{E_{F} + E_{P}}} \sum_{s} \int_{0}^{2\pi} \left[\frac{\hbar^{2} k_{Fs}^{3}}{m^{2}} \cos^{2} \phi + s \frac{2\sqrt{2}\lambda k_{Fs}^{2}}{m} \operatorname{sgn} (\cos \phi - \sin \phi) \cos \phi + \frac{2\lambda^{2} k_{Fs}}{\hbar^{2}} \right] \\ &+ \frac{\hbar^{2} k_{Fs}^{3}}{2m^{2}} \sin 2\phi \sin 2\phi - \frac{2\lambda^{2} k_{Fs}}{\hbar^{2}} \sin 2\phi - s \frac{\sqrt{2}\lambda k_{Fs}^{2}}{m} |\cos \phi - \sin \phi| \sin 2\phi | d\phi \\ &= \frac{\sqrt{me^{2} \tau \mathbf{\epsilon}}}{2\sqrt{2}\pi^{2} \hbar \sqrt{E_{F} + E_{P}}} \int_{0}^{2\pi} \left[\frac{\hbar^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{m^{2}} \left(4k_{\phi}^{2} + k_{0}^{2} - \frac{8m^{2}\lambda^{2}}{\hbar^{4}} \right) \cos^{2} \phi + \frac{4\lambda^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{\hbar^{2}} \sin 2\phi \\ &+ \frac{2\lambda^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{\hbar^{2}} (1 + \sin 2\phi) + \frac{\hbar^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{2m^{2}} \left(4k_{\phi}^{2} + k_{0}^{2} - \frac{8m^{2}\lambda^{2}}{\hbar^{4}} \right) \sin 2\phi \sin 2\phi \\ &= \frac{\sqrt{me^{2} \tau \mathbf{\epsilon}}}{2\sqrt{2}\pi^{2} \hbar \sqrt{E_{F} + E_{P}}} \int_{0}^{2\pi} \left[\frac{\hbar^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{2m^{2}} \left(4k_{\phi}^{2} + k_{0}^{2} - \frac{8m^{2}\lambda^{2}}{\hbar^{4}} \right) \sin 2\phi \sin 2\phi \right] d\phi \\ &\approx \frac{\sqrt{me^{2} \tau \mathbf{\epsilon}}}{2\sqrt{2}\pi^{2} \hbar \sqrt{E_{F} + E_{P}}} \int_{0}^{2\pi} \left[\frac{\hbar^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{2m^{2}} \left(4k_{\phi}^{2} + k_{0}^{2} - \frac{8m^{2}\lambda^{2}}{\hbar^{4}} \right) \sin 2\phi \sin 2\phi \right] d\phi \\ &+ \frac{2\lambda^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{\hbar^{2} \sqrt{E_{F} + E_{P}}} \int_{0}^{2\pi} \left[\frac{\hbar^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{2m^{2}} \left(4k_{\phi}^{2} + k_{0}^{2} - \frac{8m^{2}\lambda^{2}}{\hbar^{4}} \right) \sin 2\phi \sin 2\phi \right] d\phi \\ &+ \frac{2\lambda^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{\hbar^{2} \sqrt{E_{F} + E_{P}}} \int_{0}^{2\pi} \left[\frac{\hbar^{2} \sqrt{k_{\phi}^{2} + k_{0}^{2}}}{2m^{2}} \left(\frac{4m^{2} \lambda^{2} k_{\phi}^{2}}{\hbar^{4} k_{0}} - \frac{8m^{2} \lambda^{2} k_{0}}{\hbar^{4}} + k_{0}^{3} \right) \cos^{2}\phi + \frac{4\lambda^{2}}{\hbar^{2}} \left(k_{0} + \frac{k_{\phi}^{2}}{2k_{0}} \right) \sin 2\phi \sin 2\phi \\ &+ \frac{2\lambda^{2}}{\hbar^{2}} \left(k_{0} + \frac{k_{\phi}^{2}}{2k_{0}} \right) (1 + \sin 2\phi) + \frac{\hbar^{2}}{2m^{2}} \left(\frac{9}{2} k_{0} k_{\phi}^{2} - \frac{4m^{2} \lambda^{2} k_{\phi}^{2}}{\hbar^{4} k_{0}} - \frac{8m^{2} \lambda^{2} k_{0}}{\hbar^{4} k_{0}} + \frac{8m^{2} \lambda^{2} k_{0}}{\hbar^{4} k_{0}} \right) \sin 2\phi \sin 2\phi \\ &= \frac{e^{2} \tau \mathbf{\epsilon}}{4\pi \hbar^{2} \sqrt{E_{F} + E_{P}}} \left[4E_{F} \sqrt{E_{F} + 5E_{P} \sqrt{E_{F} - \frac{2E_{P}^{2}}{\sqrt{E_{F} + E_{P}}}} \frac{E_{P} \sqrt{E_{F} - \frac{E_{P} \sqrt{E_{F} - E_{P}}}}{2\pi k_{0}^{$$

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